

 AP2141SG-13
 AP2141SG-U
 AP2142SG-13
 AP2142SG-U
 AP2151SG-U
 AP2152SG-13
 AP2152SG-U

 AP2161SG-13
 AP2161SG-U
 AP2162SG-U
 AP2171SG-U
 AP2172SG-U
 AP2172SG-U

 AP2181SG-13
 AP2181SG-U
 AP2182SG-U
 AP2191SG-U
 AP2191SG-U
 AP2192SG-U

 AP393ASG-U
 AP393ASG-U
 AP393ASG-U
 AP5004-SG-U
 AP5004-SG-U
 AP5004-SG-U

Part Number: **SOP-8L Green** Weight (mg): 75.926

Element	Material Group	Materials	CAS (if applicable)	Average mass homogeneous Materal(%)			ppm Homogeneous Material	ppm overall
Die,Mosfet	Doped silicon	Doped silicon *	7440-21-3	100.00%	7.892	5.992	1000000	78923
SOP-8L leadframe		Cu	7440-50-8	97.40%	51.403	39.029	974000	500670
	CDA 194	Fe	1309-37-1	2.40%			24000	12337
	CDA 194	Р	7723-14-0	0.08%			800	411
		Zn	7440-66-6	0.12%			1200	617
	Pure silver	Ag	7440-22-4	100.00%	0.940	0.714	1000000	9404
Bonding wire	2.0mil	Au	7440-57-5	100.00%	0.946	0.719	1000000	9464
Molding compound		Epoxy Resin		5.00%	34.281	26.028	50000	17140
		Phenol Resin		5.00%			50000	17140
	EME-G600	Bismuth/Bismuth compound		0.05%			500	171
	LIVIL-GOOD	SiO2	60676-86-0	87.45%			874500	299785
		Cresol Novolac	29690-82-2	2.00%			20000	6856
		С	1333-86-4	0.50%			5000	1714
Die attached epoxy		Ag	7440-22-4	75.00%	2.971	2.256	750000	22281
	84-1 LMISR4	epoxy resin	Trade secret	20.00%			200000	5942
		curing agent & hardener	Trade secret	5.00%			50000	1485
Tin solder	Pure Tin	Sn	7440-31-5	100.00%	1.566	1.189	1000000	15659
					100.00	75.926		1000000

Tolerance ±10%

This data is based on information provided by our suppliers. We believe it to be correct but do not routinely validate it by measurement. It is for guidance only and Diodes Inc. does not guarantee its absolute accuracy or completeness

This product or product family does not contain any of the following substances except as CURRENTLY exempted by ELV II and RoHS and reported above:

Antimony compounds

Asbestos

Azo compounds

Cadmium and cadmium compounds

Certain Shortchain Chlorinated Paraffins Chlorinated organic compounds

Chlorinated Halogens

Hexavalent chromium compounds Lead and lead compounds

Mercury and mercury compounds

Organic tin compounds

Ozone Depleting Substances - Class I (CFCs, HBFCs, etc.)

Ozone Depleting Substances - Class II (HCFCs)

Perfluorooctane Sulphonate (PFOS) or related compounds

Polybrominated biphenyls (PBB) and Polybrominated diphenyl ethers (PBDE) includin **DecaBDE**

Polychlorinated Biphenyls (PCBs)

Polychlorinated Naphthalenes (> 3 chlorine atoms)

Radioactive Substances

Tributyl Tin (TBT) and Triphenyl Tin (TPT)

Tributyl Tin Oxide (TBTO)

^{*} The Silicon Chip is doped at atomic levels with trace amounts of elements that may include Phosphorus, Boron, Arsenic, and other elements. Metalization may include Titanium, Nickel, Aluminum, Silver or Gold These substances are not reported where their concentration is less than the minimum reportable level per the guidelines specified in the Tables of EIA JIG-101, <u>Material Composition Declaration for Electronic Products</u>.